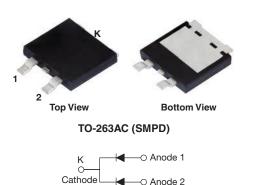
Vishay Semiconductors

Hyperfast Rectifier, 2 x 5 A FRED Pt[®]



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PRODUCT SUMMARY					
Package	TO-263AC (SMPD)				
I _{F(AV)}	2 x 5 A				
V _R	600 V				
V _F at I _F	1 V				
t _{rr}	35 ns				
T _J max.	175 °C				
Diode variation	Dual die				

FEATURES

- Hyperfast recovery time, reduced Q_{rr}, and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM / CCM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Peak repetitive reverse voltage		V _{RRM}		600	V		
Average rectified forward current	per device		T _{solder pad} = 153 °C	10			
	per diode	IF(AV)		5			
	per device	1	T 05 °C 0 m course color	110	A		
Non-repetitive peak surge current	per diode	IFSM	T _J = 25 °C, 6 ms square pulse	60			

ELECTRICAL SPECIFICATIONS ($T_J = 25 \text{ °C}$ unless otherwise specified)						
PARAMETER	SYMBOL	YMBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-	
Forward voltage, per diode	V _F	I _F = 5 A	-	1.2	1.5	V
Forward voltage, per diode		I _F = 5 A, T _J = 150 °C	-	1	1.25	
Deverse leekees eurrent ner diede		$V_{R} = V_{R}$ rated	-	-	3	
Reverse leakage current, per diode		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	15	150	μA
Junction capacitance, per diode	CT	V _R = 600 V	-	6	-	pF

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FREE



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DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 50 \text{ A}$	õs, V _R = 30 V	-	35	-	
Reverse recovery time	+	$I_{F} = 0.5 \text{ A}, I_{R} = 1 \text{ A}, I_{rr}$	-	-	35		
Reverse recovery time	t _{rr}	T _J = 25 °C		-	45	-	ns
		T _J = 125 °C		-	70	-	
Deck receiver a surrent		T _J = 25 °C	$I_{\rm F} = 5 {\rm A},$	-	7	-	^
Peak recovery current	I _{RRM}	T _J = 125 °C	dI _F /dt = 500 A/µs, V _R = 400 V	-	10	-	A
D	Q _{rr}	T _J = 25 °C]	-	160	-	
Reverse recovery charge		T _J = 125 °C		-	370	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	+175	°C	
Thermal resistance, per diode junction to solder pad	R _{thJ-Sp}		-	2.4	3.3	°C/W	
Approximate weight				0.55		g	
Approximate weight				0.02		oz.	
Marking device		Case style TO-263AC (SMPD)		10CI	DH06		

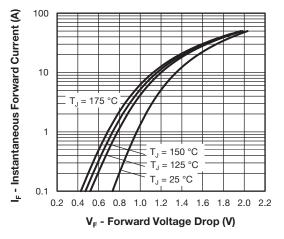


Fig. 1 - Typical Forward Voltage Drop Characteristics

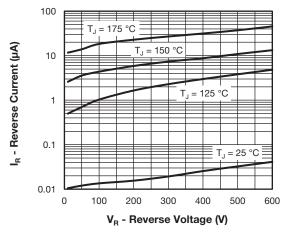


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

VS-10CDH06-M3

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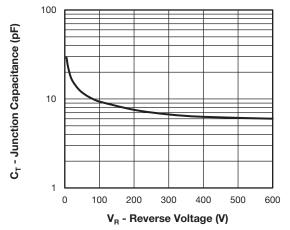


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

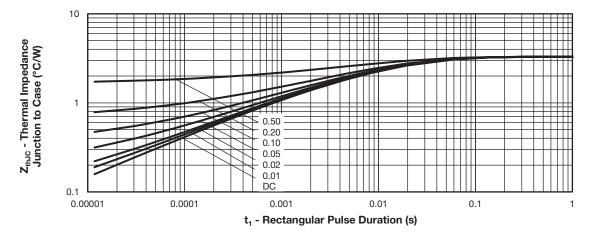
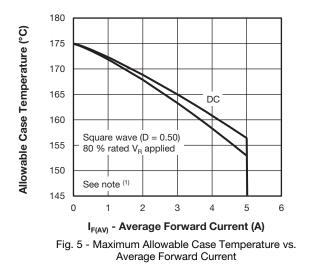
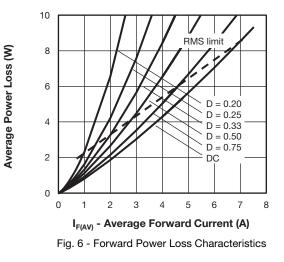


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 5); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; $I_R at V_{R1} = rated V_R$

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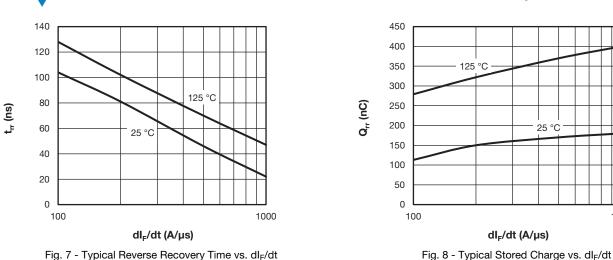
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1000

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25 °C



SHAY

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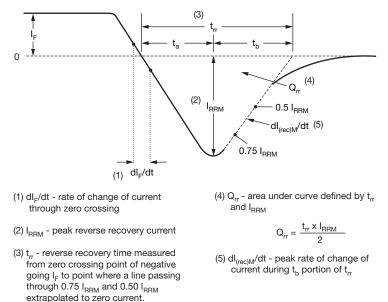


Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	10	С	D	н	06	-M3	
	1	2	3	4	5	6	7	
	1	- Visl	nay Sen	nicondu	ctors pr	oduct		
	2 -	- Cur	rent rati	ing (10 A	4)			
	3 -	- Circ	cuit con	figuratio	n:			
		C =	commo	on catho	de			
	4	• D =	SMPD	packag	е			
	5 -	- Pro	cess typ	be,				
		H = hyperfast recovery						
	6	- Volt	tage coo	de (06 =	600 V)			
	7	-M3	3 = halog	gen-free	e, RoHS	-compli	iant, and	

ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER REEL MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION						
VS-10CDH06-M3/I	2000	2000	13" diameter plastic tape and reel				

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95604				
Part marking information	www.vishay.com/doc?95566				
Packaging information	www.vishay.com/doc?88869				



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